High Surge Current Two-pin SIDACtor® Device







This *SIDACtor* device is intended for very hostile environments such as CATV (Community Antenna TV) systems and electronics connected to external antennas.

Electrical Parameters

Part Number *	V _{DRM} Volts	V _S Volts	V _T Volts	I _{DRM} μAmps	I _S mAmps	I _T Amps	I _H mAmps
P1400ADL	120	160	3	5	800	2.2	50
P1800ADL	170	220	3	5	800	2.2	50

^{* &}quot;L" in part number indicates RoHS compliance. For non-RoHS compliant device, delete "L" from part number. For surge ratings, see table below.

General Notes:

- All measurements are made at an ambient temperature of 25 °C. IPP applies to -40 °C through +85 °C temperature range.
- IPP is a repetitive surge rating and is guaranteed for the life of the product.
- · Listed SIDACtor devices are bi-directional. All electrical parameters and surge ratings apply to forward and reverse polarities.
- V_{DRM} is measured at I_{DRM}.
- V_S is measured at 100 V/μs.
- Special voltage (V_S and V_{DRM}) and holding current (I_H) requirements are available upon request.

Surge Ratings in Amps

	I _{PP}			
	8x20 * 1.2x50 **	10x1000 * 10x1000 **	I _{TSM} 50 / 60 Hz	di/dt
Series	Amps	Amps	Amps	Amps/μs
D	1000	250	120	500

^{*} Current waveform in µs

^{**} Voltage waveform in µs



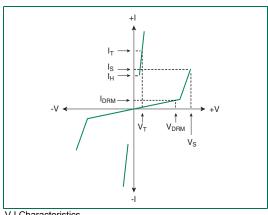
Thermal Considerations

Package	Symbol	Parameter	Value	Unit
	T_J	Operating Junction Temperature Range	-40 to +150	°C
Modified TO-220	T _S	Storage Temperature Range	-65 to +150	°C
1 3	R _θ JA	Thermal Resistance: Junction to Ambient	60	°C/W

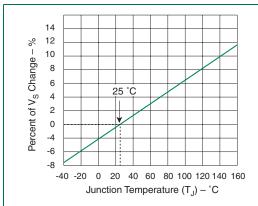
Capacitance Values

	pF		
Part Number	MIN	MAX	
P1400ADL	140	200	
P1800ADL	120	180	

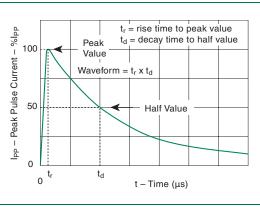
Note: Off-state capacitance (C_{O}) is measured at 1 MHz with a 2 V bias.



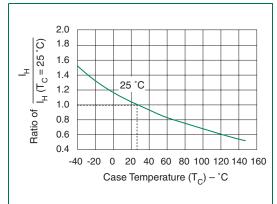
V-I Characteristics



Normalized V_S Change versus Junction Temperature



t_r x t_d Pulse Waveform



Normalized DC Holding Current versus Case Temperature